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May 2012

FDS86540

N-Channel PowerTrench $^{\mbox{\scriptsize R}}$ MOSFET 60 V, 18 A, 4.5 m Ω

Features

- Max $r_{DS(on)} = 4.5 \text{ m}\Omega$ at $V_{GS} = 10 \text{ V}$, $I_D = 18 \text{ A}$
- Max $r_{DS(on)} = 5.4 \text{ m}\Omega$ at $V_{GS} = 8 \text{ V}$, $I_D = 16.5 \text{ A}$
- High performance trench technologh for extremely low r_{DS(on)}
- High power and current handing capability in a widely used surface mount package
- 100% UIL Tested
- RoHS Compliant

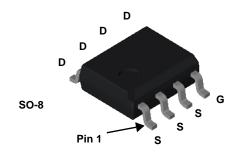


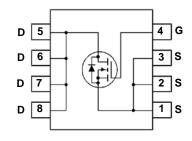
General Description

This N-Channel MOSFET has been designed specifically to improve the overall efficiency and to minimize switch node ringing of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low $r_{DS(on)}$, fast switching speed and body diode reverse recovery performance.

Applications

- Primary Switch in isolated DC-DC
- Synchronous Rectifier
- Load Switch





MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Paramete		Ratings	Units	
V _{DS}	Drain to Source Voltage			60	V
V_{GS}	Gate to Source Voltage			±20	V
1	Drain Current -Continuous			18	^
ID	-Pulsed			120	Α
E _{AS}	Single Pulse Avalanche Energy		(Note 3)	194	mJ
Б	Power Dissipation $T_C = 25 ^{\circ}\text{C}$ (Note 1)		(Note 1)	5.0	W
P_{D}	Power Dissipation $T_A = 25 ^{\circ}\text{C}$ (Note 1a)			2.5	VV
T _J , T _{STG}	Operating and Storage Junction Temperature Range			-55 to +150	°C

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction to Case	(Note 1)	25	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	50	C/VV

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDS86540	FDS86540	SO-8	13"	12 mm	2500 units

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Electrical Characteristics T_J = 25 °C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units		
Off Chara	Off Characteristics							
BV_{DSS}	Drain to Source Breakdown Voltage	$I_D = 250 \mu A, V_{GS} = 0 V$	60			V		
$\frac{\Delta BV_{DSS}}{\Delta T_{J}}$	Breakdown Voltage Temperature Coefficient	I_D = 250 μ A, referenced to 25 °C		28		mV/°C		
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 48 V, V _{GS} = 0 V			1	μΑ		
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA		

On Characteristics

V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	2	3.1	4	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \mu A$, referenced to 25 °C		-11		mV/°C
		V _{GS} = 10 V, I _D = 18 A		3.7	4.5	
r _{DS(on)}		$V_{GS} = 8 \text{ V}, I_D = 16.5 \text{ A}$		4.2	5.4	mΩ
, ,		V _{GS} = 10 V, I _D = 18 A, T _J = 125 °C		5.9	7	
9 _{FS}	Forward Transconductance	V _{DS} = 10 V, I _D = 18 A		69		S

Dynamic Characteristics

C _{iss}	Input Capacitance	V 20 V V 0 V	4820	6410	pF
C _{oss}	Output Capacitance	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1 MHz	1610	2145	pF
C _{rss}	Reverse Transfer Capacitance	1 - 1 101112	67	130	pF
R_g	Gate Resistance		0.6		Ω

Switching Characteristics

t _{d(on)}	Turn-On Delay Time		28	45	ns
t _r	Rise Time	V _{DD} = 30 V, I _D = 18 A,	15	27	ns
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = 10 \text{ V}, R_{GEN} = 6 \Omega$	33	53	ns
t _f	Fall Time		7.1	15	ns
Q_g	Total Gate Charge	V _{GS} = 0 V to 10 V	65	90	nC
Q_g	Total Gate Charge	$V_{GS} = 0 \text{ V to 8 V} V_{DD} = 30 \text{ V},$	53	75	nC
Q_{gs}	Gate to Source Charge	I _D = 18 A	22		nC
Q_{gd}	Gate to Drain "Miller" Charge		13		nC

Drain-Source Diode Characteristics

Ven Source-Drain Dioge Forward Voltage	$V_{GS} = 0 \text{ V}, I_{S} = 18 \text{ A}$ (Note 2)		0.8	1.3	V	
	$V_{GS} = 0 \ V, I_{S} = 2 \ A$ (Note 2)		0.7	1.2	v	
t _{rr}	Reverse Recovery Time	I _F = 18 A, di/dt = 100 A/μs		57	92	ns
Q _{rr}	Reverse Recovery Charge			44	71	nC

NOTES:

^{1.} $R_{\theta,IA}$ is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. $R_{\theta,IC}$ is guaranteed by design while $R_{\theta,CA}$ is determined by the user's board design.



a) 50 °C/W when mounted on a 1 in² pad of 2 oz copper.



b) 125 °C/W when mounted on a minimum pad.

^{2.} Pulse Test: Pulse Width < 300 μs , Duty cycle < 2.0%. 3. Starting T $_J$ = 25 °C, $\,$ L = 0.3 mH, I $_{AS}$ = 36 A, V $_{DD}$ = 54 V, V $_{GS}$ = 10 V.

Typical Characteristics T_J = 25 °C unless otherwise noted

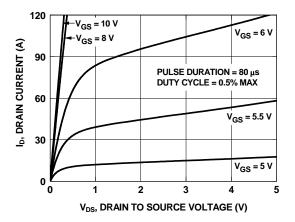


Figure 1. On-Region Characteristics

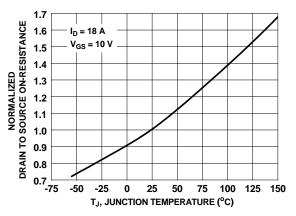


Figure 3. Normalized On-Resistance vs Junction Temperature

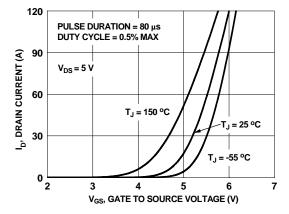


Figure 5. Transfer Characteristics

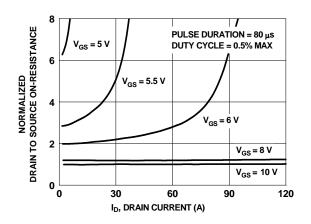


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

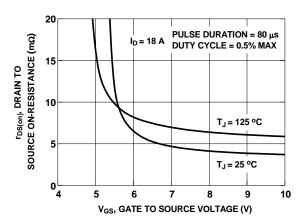


Figure 4. On-Resistance vs Gate to Source Voltage

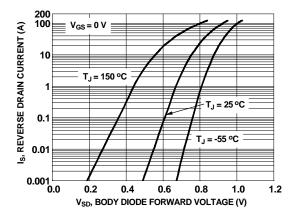


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

Typical Characteristics $T_J = 25$ °C unless otherwise noted

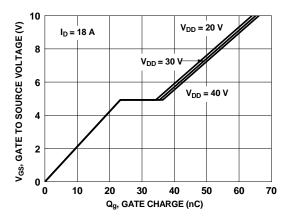


Figure 7. Gate Charge Characteristics

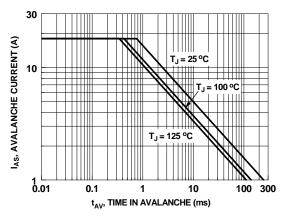


Figure 9. Unclamped Inductive Switching Capability

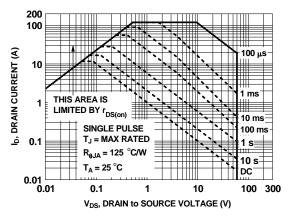


Figure 11. Forward Bias Safe Operating Area

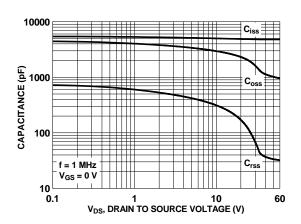


Figure 8. Capacitance vs Drain to Source Voltage

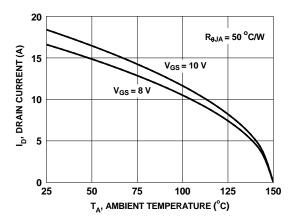


Figure 10. Maximum Continuous Drain Current vs Ambient Temperature

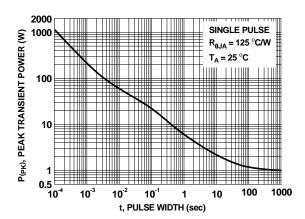


Figure 12. Single Pulse Maximum Power Dissipation

Typical Characteristics $T_J = 25$ °C unless otherwise noted

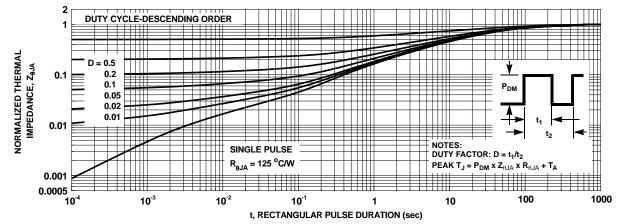


Figure 13. Junction-to-Ambient Transient Thermal Response Curve





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